# Analog Switch, Dual DPDT, Ultra-Low R<sub>ON</sub>

The NLAS3799 is an ultra-low R<sub>ON</sub> DPDT and a 0.5  $\Omega$  R<sub>ON</sub> DPDT analog switch. This device is designed for low operating voltage, high current switching of speaker output and earpiece for cellphone applications. It can switch a balanced stereo output. The NLAS3799 can handle a balanced microphone/speaker/ring-tone generator in a monophone mode. The device contains a break-before-make (BBM) feature.

### Features

- Single Supply Operation 1.65 to 3.6 V V<sub>CC</sub>
- Maximum Breakdown Voltage: 4.6 V
- Low Static Power
- NLAS3799 Interfaces with 2.8 V Chipset NLAS3799L Interfaces with 1.8 V Chipset
- These are Pb-Free Devices\*

### **Typical Applications**

- Cell Phone Speaker/Microphone Switching
- Ringtone–Chip/Amplifier Switching
- Four Unbalanced (Single-Ended) Switches
- Stereo Balanced (Push-Pull) Switching

### Important Information

- ESD Protection:
  - Human Body Model (HBM) > 8000 V Machine Model (MM) > 400 V
- Continuous Current Rating Through each Switch ±300 mA
- Conforms to: JEDEC MO-220, Issue H, Variation VEED-6
- Package: 1.8 x 2.6 x 0.75 mm WQFN-16 Pb-Free



### **ON Semiconductor®**

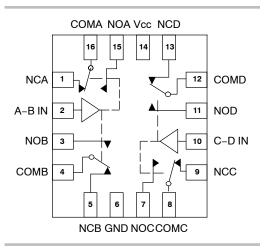
http://onsemi.com





MARKING

- XX = Specific Device Code AR = NLAS3799 AT = NLAS3799L
- M = Date Code/Assembly Location
  - = Pb-Free Package



### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

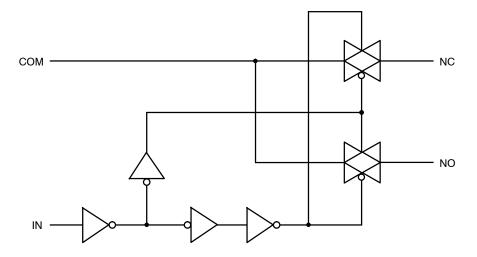


Figure 1. Input Equivalent Circuit

### **PIN DESCRIPTION**

QFN PIN #	Symbol	Name and Function
1, 3, 5, 7, 9, 11, 13, 15	NO A-D, NC A-D	Independent Channels
2, 10	A–B IN, C–D IN	Controls
4, 8, 12, 16	COM A-D	Common Channels
6	GND	Ground (V)
14	V <sub>CC</sub>	Positive Supply Voltage

### TRUTH TABLE

IN	NO	NC		
н	ON	OFF*		
L	OFF*	ON		

\*High impedance.

### MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +4.6	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub> , V <sub>NC</sub> , or V <sub>COM</sub> )	$-0.5 \leq V_{IS} \leq V_{CC} + 0.5$	V
V <sub>IN</sub>	Digital Select Input Voltage	$-0.5 \le V_{IN} \le +V_{CC}$	V
I <sub>anl1</sub>	Continuous DC Current from COM to NC/NO	±300	mA
I <sub>anl-pk1</sub>	Peak Current from COM to NC/NO, 10 Duty Cycle (Note 1)	±500	mA
I <sub>cImp</sub>	Continuous DC Current into COM/NO/NC with Respect to $V_{CC}$ or GND	±100	mA
Τ <sub>S</sub>	Storage Temperature	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% OFF Duty Cycle.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Мах	Unit
V <sub>CC</sub>	DC Supply Voltage	1.65	3.6	V
V <sub>IN</sub>	Digital Select Input Voltage	GND	V <sub>CC</sub>	V
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)	GND	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, IN $V_{CC} = 1.6 \text{ V} - 2.7 \text{ V} \\ V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$		20 10	ns/V

### NLAS3799 DC CHARACTERISTICS - DIGITAL SECTION (Voltages Referenced to GND)

				Guara	anteed Limit	
Symbol	Parameter	Condition	Vcc	25°C	–40°C to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 3.6	1.4 1.7	1.4 1.7	V
V <sub>IL</sub>	Maximum Low-Level Input Voltage, Select Inputs		3.0 3.6	0.5 0.5	0.5 0.5	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 3.6 V or GND	0	±0.5	±2.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 2)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 3.6	±1.0	±2.0	μΑ

2. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

### NLAS3799 DC ELECTRICAL CHARACTERISTICS - ANALOG SECTION

				Gua	ranteed	Maximun	n Limit	
				25°C		–40°C to +85°C		
Symbol	Parameter	Condition	V <sub>CC</sub>	Min	Max	Min	Max	Unit
R <sub>ON</sub>	NC/NO On-Resistance (Note 3)		3.0 3.6		0.5 0.4		0.5 0.4	Ω
R <sub>FLAT</sub>	NC/NO On-Resistance Flatness (Notes 3 and 4)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 3.6		0.15 0.15		0.15 0.15	Ω
ΔR <sub>ON</sub>	On-Resistance Match Between Channels (Notes 3 and 5)		3.0 3.6		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 3)	$ \begin{array}{l} V_{IN} = V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} = 0.3 \text{ V} \\ V_{COM} = \ 3.3 \text{ V} \end{array} $	3.6	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 3)	$ \begin{array}{l} V_{IN} = V_{IL} \mbox{ or } Y_{IH} \\ V_{NO} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NC} \mbox{ floating or} \\ V_{NC} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NO} \mbox{ floating} \\ V_{COM} = \mbox{ 0.3 V or } 3.3 \mbox{ V} \end{array} $	3.6	-10	10	-100	100	nA

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

4. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

5.  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$  between nS2 or nS1.

				Guara	anteed Limit	
Symbol	Parameter	Condition	V <sub>CC</sub>	25°C	–40 to +85°C	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage, Select Inputs		3.0 3.6	1.2 1.3	1.2 1.3	V
V <sub>IL</sub>	Maximum Low-Level Input Voltage, Select Inputs		3.0 3.6	0.5 0.5	0.5 0.5	V
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	±0.1	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 3.6 V or GND	0	±0.5	±2.0	μA
Icc	Maximum Quiescent Supply Current (Note 6)	Select and $V_{IS} = V_{CC}$ or GND	1.65 to 3.6	±10	±20	μΑ

### NLAS3799L DC CHARACTERISTICS – DIGITAL SECTION (Voltages Referenced to GND)

6. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

#### NLAS3799L DC ELECTRICAL CHARACTERISTICS - ANALOG SECTION

				Gua	ranteed	Maximun	n Limit	
				25°C –4		–40°C te	–40°C to +85°C	
Symbol	Parameter	Condition	Vcc	Min	Max	Min	Max	Unit
R <sub>ON</sub>	NC/NO On-Resistance (Note 7)		3.0 3.6		0.5 0.5		0.5 0.5	Ω
R <sub>FLAT</sub>	NC/NO On-Resistance Flatness (Notes 7 and 8)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	3.0 3.6		0.15 0.15		0.15 0.15	Ω
ΔR <sub>ON</sub>	On-Resistance Match Between Channels (Notes 7 and 9)		3.0 3.6		0.05 0.05		0.05 0.05	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Note 7)	$\begin{array}{l} V_{\text{IN}} = V_{\text{IL}} \text{ or } V_{\text{IH}} \\ V_{\text{NO}} \text{ or } V_{\text{NC}} = 0.3 \text{ V} \\ V_{\text{COM}} = 3.3 \text{ V} \end{array}$	3.6	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Note 7)	$ \begin{array}{l} V_{IN} = V_{IL} \mbox{ or } Y_{IH} \\ V_{NO} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NC} \mbox{ floating or } \\ V_{NC} \mbox{ 0.3 V or } 3.3 \mbox{ V with} \\ V_{NO} \mbox{ floating } \\ V_{COM} = \mbox{ 0.3 V or } 3.3 \mbox{ V} \end{array} $	3.6	-10	10	-100	100	nA

7. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

8. Flatness is defined as the difference between the maximum and minimum value of On-resistance as measured over the specified analog signal ranges.

9.  $\Delta \breve{R}_{ON} = \breve{R}_{ON(MAX)} - R_{ON(MIN)}$  between NC1 and NC2 or between NO1 and NO2.

### NLAS3799/NLAS3799L AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

					Gua	rantee	d Maxi	mum L	.imit	
			V <sub>CC</sub> V <sub>IS</sub>			25°C			°C to 5°C	
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Unit
t <sub>ON</sub>	Turn–On Time	$R_L = 50 \ \Omega$ , $C_L = 35 \ pF$ (Figures 3 and 4)	2.3 - 3.6	1.5			50		60	ns
t <sub>OFF</sub>	Turn–Off Time	$R_L = 50 \Omega$ , $C_L = 35 pF$ (Figures 3 and 4)	2.3 - 3.6	1.5			30		40	ns
t <sub>BBM</sub>	Minimum Break-Before-Make Time	$\begin{array}{l} V_{IS} = 3.0 \\ R_L = 50 \; \Omega, \; C_L = 35 \; pF \\ (Figure \; 2) \end{array}$	3.0	1.5	2	15				ns

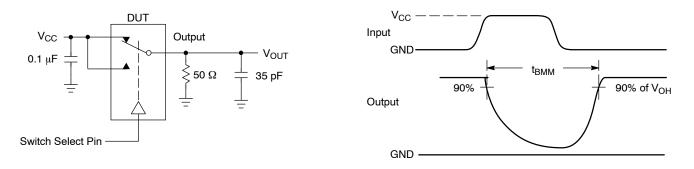
		Typical @ 25, V <sub>CC</sub> = 3.6 V	
C <sub>IN</sub>	Control Pin Input Capacitance	3.0	pF
C <sub>SN</sub>	SN Port Capacitance	72	pF
CD	D Port Capacitance When Switch is Enabled	220	pF

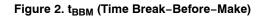
\*Typical Characteristics are at 25°C.

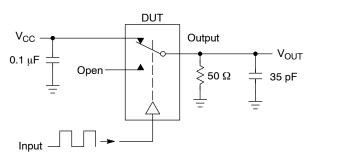
### ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			V <sub>cc</sub>	25°C	
Symbol	Parameter	Condition	(V)	Typical	Unit
BW	Maximum On-Channel -3 dB Bandwidth or Minimum Frequency Response (Figure 9)	$V_{\text{IN}}$ centered between $V_{\text{CC}}$ and GND (Figure 5)	1.65 – 3.6	19	MHz
V <sub>ONL</sub>	Maximum Feed-through On Loss	$V_{IN}$ = 0 dBm @ 100 kHz to 50 MHz $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 3.6	-0.06	dB
V <sub>ISO</sub>	Off-Channel Isolation	$f$ = 100 kHz; $V_{IS}$ = 1 V RMS; $C_L$ = 5.0 pF $V_{IN}$ centered between $V_{CC}$ and GND(Figure 5)	1.65 – 3.6	-69	dB
Q	Charge Injection Select Input to Common I/O (Figure 8)	$V_{IN} = V_{CC to} \text{ GND, } R_{IS} = 0 \Omega, C_L = 1.0 \text{ nF}$ Q = C <sub>L</sub> x $\Delta V_{OUT}$ (Figure 6)	1.65 – 3.6	42	рС
THD	Total Harmonic Distortion THD + Noise (Figure 7)	$F_{IS}$ = 20 Hz to 20 kHz, $R_L$ = $R_{gen}$ = 600 $\Omega,$ $C_L$ = 50 pF $V_{IS}$ = 2 $V_{PP}$	3.0	0.11	%
VCT	Channel-to-Channel Crosstalk (Figure 10)	$f$ = 100 kHz; $V_{IS}$ = 1.0 V RMS, $C_L$ = 5.0 pF, $R_L$ = 50 $\Omega$ $V_{IN}$ centered between $V_{CC}$ and GND (Figure 5)	1.65 – 3.6	-90	dB

10. Off-Channel Isolation = 20log10 ( $V_{COM}/V_{NO}$ ),  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.







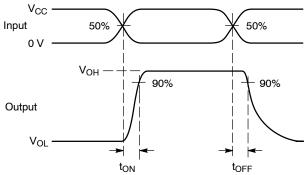
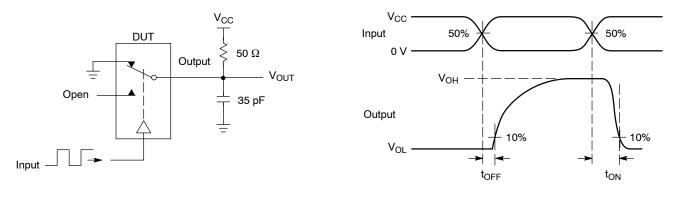
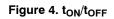
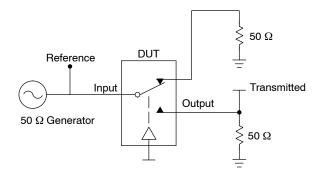


Figure 3. t<sub>ON</sub>/t<sub>OFF</sub>



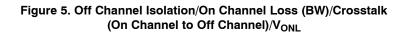




Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{ISO}$ , Bandwidth and  $V_{ONL}$  are independent of the input signal direction.

$$\begin{split} V_{ISO} &= \text{Off Channel Isolation} = 20 \ \text{Log} \left( \frac{V_{OUT}}{V_{IN}} \right) \ \text{for } V_{IN} \text{ at } 100 \ \text{kHz} \\ V_{ONL} &= \text{On Channel Loss} = 20 \ \text{Log} \left( \frac{V_{OUT}}{V_{IN}} \right) \ \text{for } V_{IN} \text{ at } 100 \ \text{kHz} \text{ to } 50 \ \text{MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V<sub>ONL</sub> V<sub>CT</sub> = Use V<sub>ISO</sub> setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 



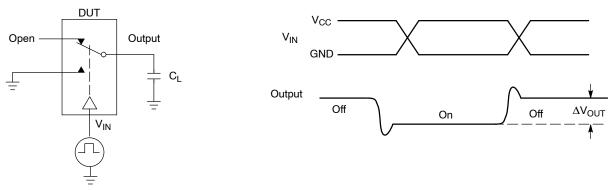
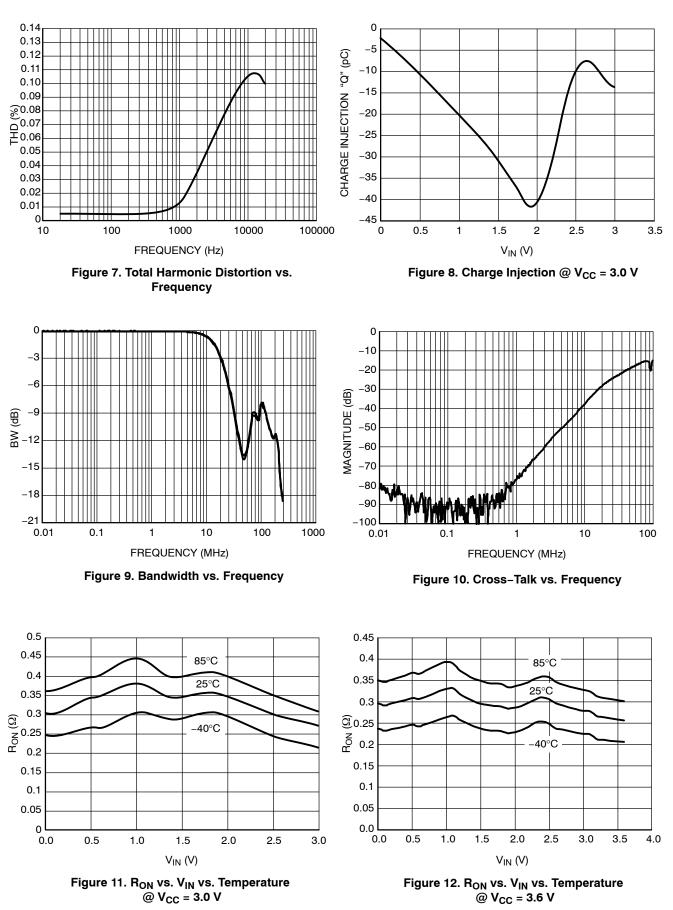


Figure 6. Charge Injection: (Q)

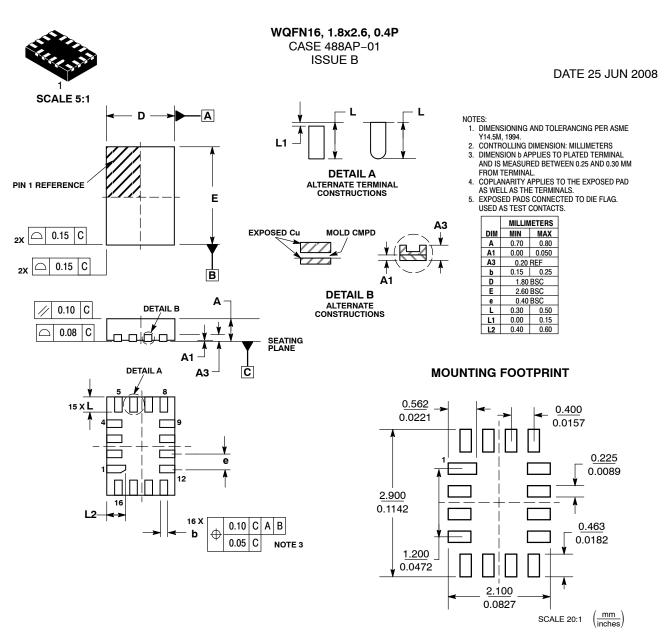


### **DEVICE ORDERING INFORMATION**

		Devi	ce Nomenc	lature			
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Tape & Reel Size <sup>†</sup>
NLAS3799MNR2G	NL	AS	3799	MN	R2	WQFN (Pb-Free)	3000 / Tape & Reel
NLAS3799LMNR2G	NL	AS	3799L	MN	R2	WQFN (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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